

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized applications, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an equif prese

October 2013

FAIRCHILD

SEMICONDUCTOR

ISL9V5045S3S / ISL9V5045S3 **EcoSPARK® N-Channel Ignition IGBT**

500mJ, 450V

Features

- SCIS Energy = 500mJ at T₁ = 25°C
- Logic Level Gate Drive

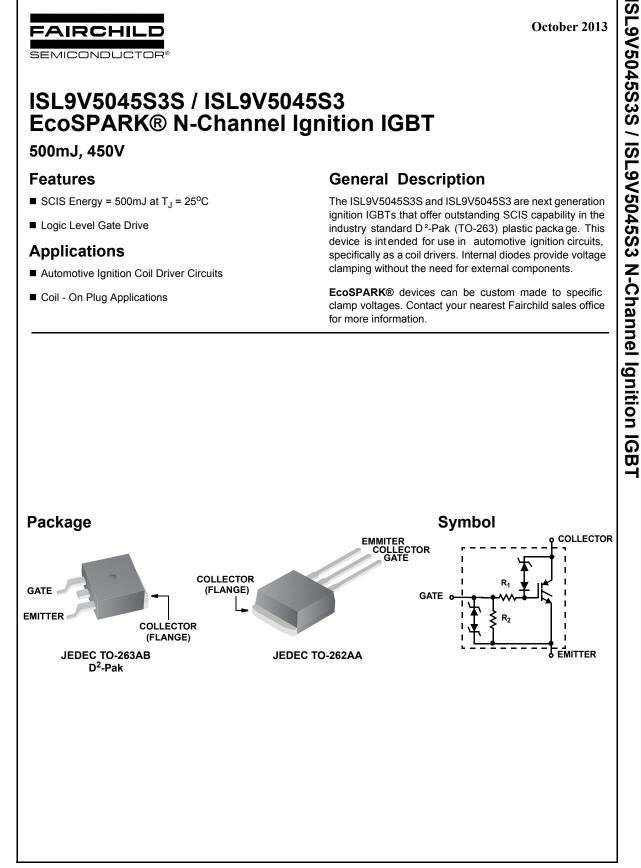
Applications

- Automotive Ignition Coil Driver Circuits
- Coil On Plug Applications

General Description

The ISL9V5045S3S and ISL9V5045S3 are next generation ignition IGBTs that offer outstanding SCIS capability in the industry standard D²-Pak (TO-263) plastic package. This device is intended for use in automotive ignition circuits, specifically as a coil drivers. Internal diodes provide voltage clamping without the need for external components.

EcoSPARK® devices can be custom made to specific clamp voltages. Contact your nearest Fairchild sales office for more information.



Symbol	Parameter	Ratings	Units V	
BV _{CER}	Collector to Emitter Breakdown Voltage (I _C = 1 mA)	480		
BV _{ECS}	Emitter to Collector Voltage - Reverse Battery Condition (I _C = 10 mA)	24	V	
E _{SCIS25}	At Starting T _J = 25°C, I _{SCIS} = 39.2A, L = 650 μHy	500	mJ	
E _{SCIS150}	At Starting T _J = 150°C, I _{SCIS} = 31.1A, L = 650 μHy	315	mJ	
I _{C25}	Collector Current Continuous, At T _C = 25°C, See Fig 9	51	Α	
I _{C110}	Collector Current Continuous, At T _C = 110°C, See Fig 9	43	Α	
V_{GEM}	Gate to Emitter Voltage Continuous	±10	V	
PD	Power Dissipation Total T _C = 25°C	300	W	
	Power Dissipation Derating T _C > 25°C	2	W/°C	
ТJ	Operating Junction Temperature Range	-40 to 175	°C	
T _{STG}	Storage Junction Temperature Range	-40 to 175	°C	
ΤL	Max Lead Temp for Soldering (Leads at 1.6mm from Case for 10s)	300	°C	
T _{pkg}	Max Lead Temp for Soldering (Package Body for 10s)	260	°C	
ESD	Electrostatic Discharge Voltage at 100pF, 1500 Ω	4	kV	

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
V5045S	5045S ISL9V5045S3ST TO-263AB 33		330mm	24mm	800
V5045S	ISL9V5045S3	TO-262AA	Tube	N/A	50
V5045S	ISL9V5045S3S TO-263AB		Tube	N/A	50

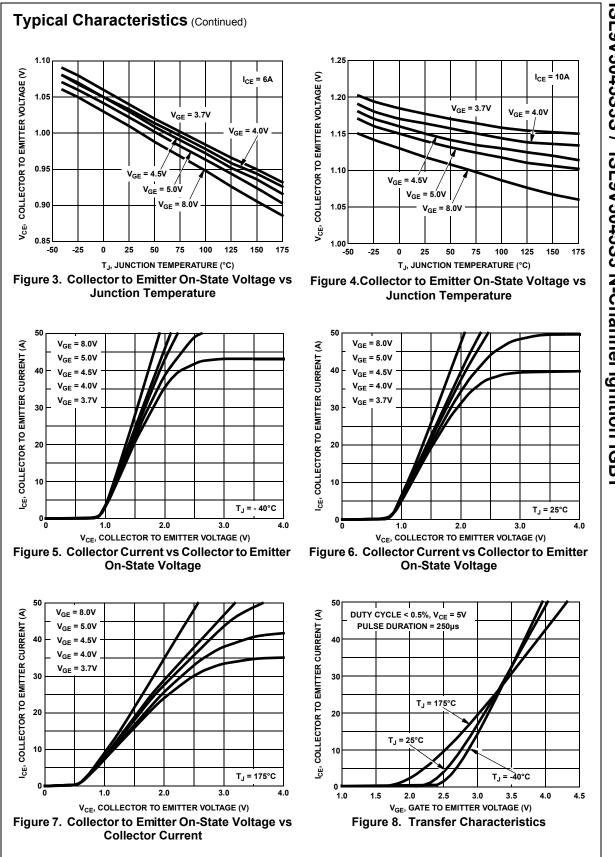
Electrical Characteristics $T_A = 25^{\circ}C$ unless otherwise noted

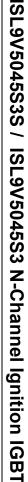
Symbol	Parameter	Test Conditions		Min	Тур	Max	Units
ff State	Characteristics						
BV _{CER}	Collector to Emitter Breakdown Voltage	I_{C} = 2mA, V _{GE} = 0, R _G = 1KΩ, See Fig. 15 T _J = -40 to 150°C		420	450	480	V
BV _{CES}	Collector to Emitter Breakdown Voltage	I_{C} = 10mA, V_{GE} = 0, R _G = 0, See Fig. 15 T _J = -40 to 150°C		445	475	505	V
BV _{ECS}	Emitter to Collector Breakdown Voltage	$I_{C} = -75$ mA, $V_{GE} = 0$ V, $T_{C} = 25^{\circ}$ C		30	-	-	V
BV _{GES}	Gate to Emitter Breakdown Voltage	I _{GES} = ± 2mA		±12	±14	-	V
I _{CER}	I _{CER} Collector to Emitter Leakage Current	V _{CER} = 320V, R _G = 1KΩ, See Fig. 11	T _C = 25°C	-	-	25	μA
			T _C = 150°C	-	-	1	mA
I _{ECS}	Emitter to Collector Leakage Current	V _{EC} = 24V, See	T _C = 25°C	-	-	1	mA
		Fig. 11	T _C = 150°C	-	-	40	mA
R ₁	Series Gate Resistance			-	100	-	Ω
R_2	Gate to Emitter Resistance			10K	-	30K	Ω
n State	Characteristics						
V _{CE(SAT)}	Collector to Emitter Saturation Voltage	I _C = 10A, V _{GE} = 4.0V	T _C = 25°C, See Fig. 4	-	1.25	1.60	V
V _{CE(SAT)}	Collector to Emitter Saturation Voltage	I _C = 15A,	T _C = 150°C	-	1.47	1.80	V

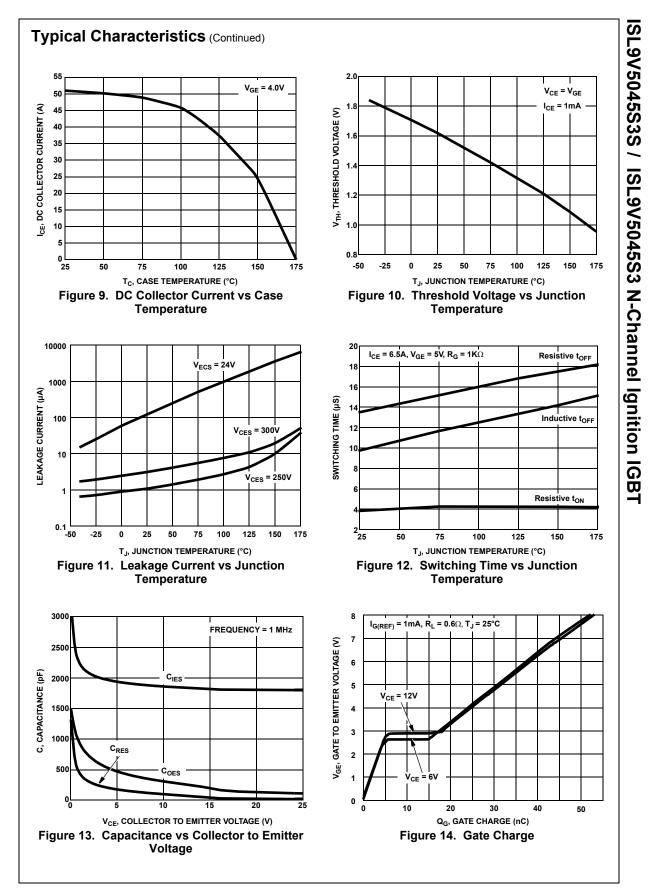
V_{GE} = 4.5V

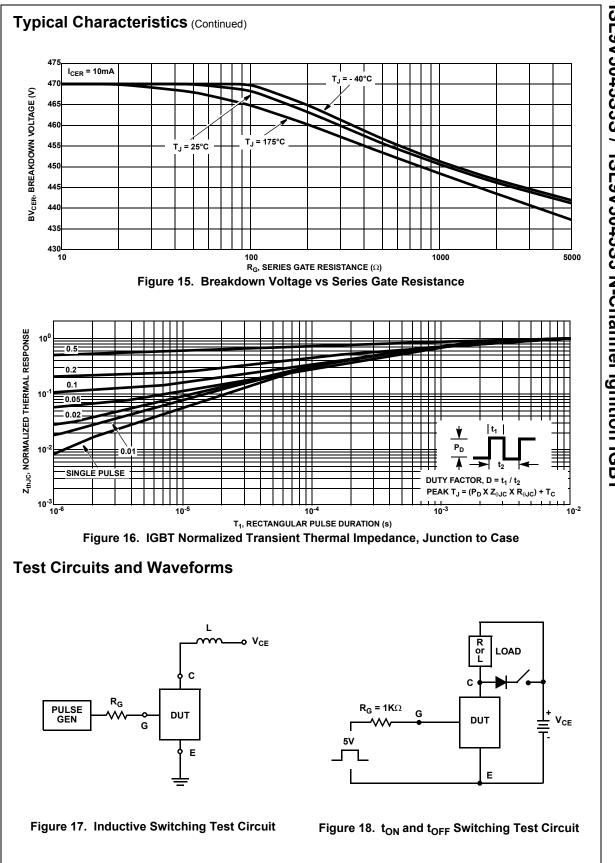
ຊ _{G(ON)}	Gate Charge	I _C = 10A, V _{CE} = V _{GE} = 5V, See		-	32	-	nC
/ _{GE(TH)}	Gate to Emitter Threshold Voltage	I _C = 1.0mA, V _{CE} = V _{GE} ,	$T_{\rm C} = 25^{\circ}{\rm C}$ $T_{\rm C} = 150^{\circ}{\rm C}$	1.3 0.75	-	2.2 1.8	V V
V _{GEP}	Gate to Emitter Plateau Voltage	See Fig. 10 I _C = 10A, V _{CE} = 12V		-	3.0	-	V
	g Characteristics		- CE - E - E - E		0.0	L	
d(ON)R	Current Turn-On Delay Time-Resistive	V _{CE} = 14V, R _L	= 1Ω,	-	0.7	4	μs
t _{rR}	Current Rise Time-Resistive	$V_{GE} = 5V, R_G = 1K\Omega$ - 2.1 T _J = 25°C, See Fig. 12			7	μs	
d(OFF)L	Current Turn-Off Delay Time-Inductive	V _{CE} = 300V, L = 2mH, - 10.8		15	μs		
t _{fL}	Current Fall Time-Inductive	V _{GE} = 5V, R _G = 1KΩ T _J = 25°C, See Fig. 12			2.8	15	μs
SCIS	Self Clamped Inductive Switching	$T_J = 25^{\circ}C, L = 650 \mu H,$ $R_G = 1K\Omega, V_{GE} = 5V, See$ Fig. 1 & 2			-	500	mJ
ermal (Characteristics	1 -					
$R_{\theta JC}$	Thermal Resistance Junction-Case	TO-263, TO-26	62	-	-	0.5	°C/W
30 25	T _J = 25°C			'J = 25°C			
25 20 15 10 5 0 0	T _J = 25°C T _J = 25°C T _J = 150°C SCIS Curves valid for V _{clamp} Voltages of <480V 25 50 75 100 125 150 175 t _{CLP} TIME IN CLAMP (μ S) 1. Self Clamped Inductive Switchin Current vs Time in Clamp	25 20 15 10 1 ^{8CISI} INDUCTIVE SWITCHING CL 18 200 0 0 0 0 0 0 0 0 0 0	SCIS Curve 0 1 2 ure 2. Self C	s valid for V 3 4	5 6 ANCE (mHy Inductiv	7 8 /) ve Switc	9 10

ISL9V5045S3S / ISL9V5045S3 N-Channel Ignition IGBT

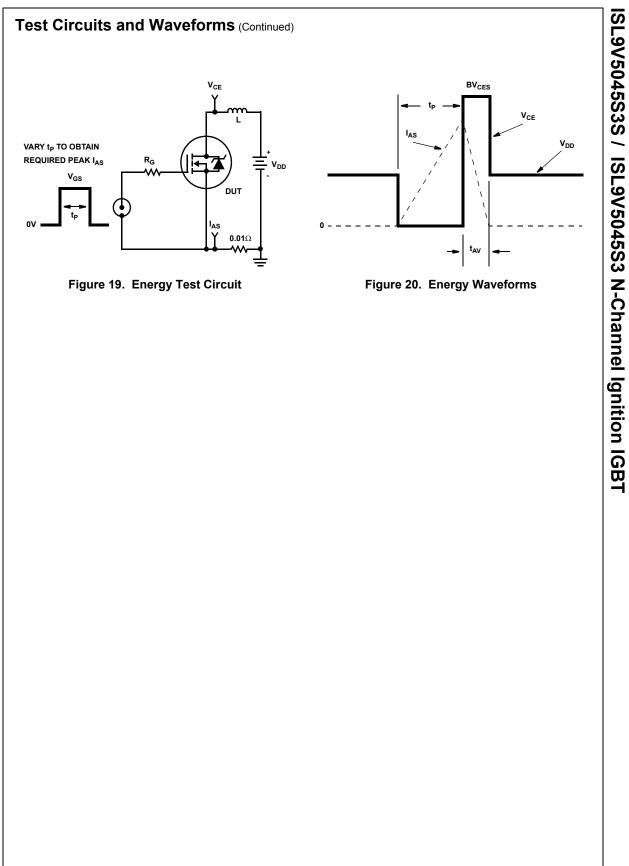


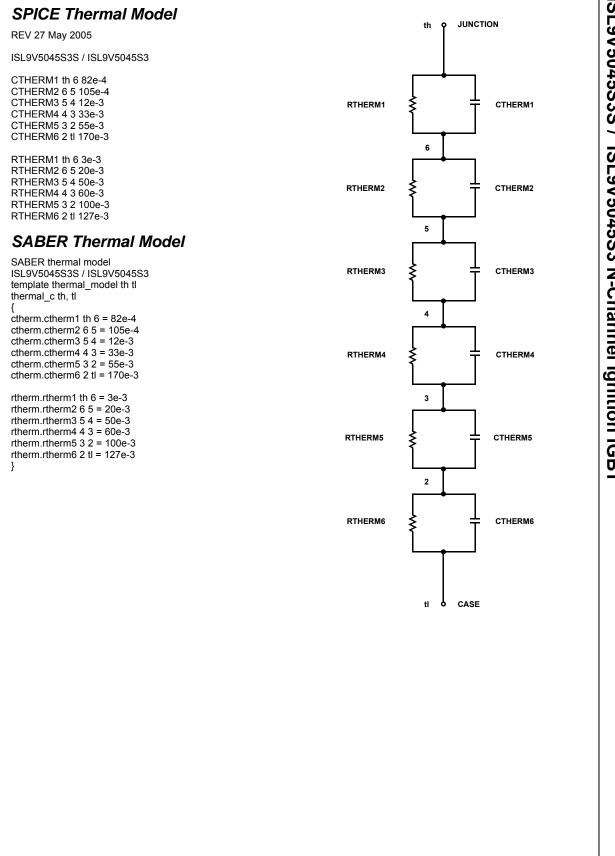






ISL9V5045S3S / ISL9V5045S3 N-Channel Ignition IGBT





FAIRCHILD

SEMICONDUCTOR

TRADEMARKS

AccuPower™

Build it Now™

CorePLUS™

DEUXPEED®

Dual Cool™

EcoSPARK[®]

EfficientMax™

R

Fairchild®

FACT

FPS™

FAST®

FastvCore™

FETBench™

ESBC™

CorePOWER™

CROSSVOLT™

Current Transfer Logic™

Fairchild Semiconductor®

FACT Quiet Series™

AX-CAP®,

BitSiC™

CTL™

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

F-PFS™ FRFET® Global Power Resource[™] GreenBridge™ Green FPS™ Green FPS™ e-Series™ Gmax™ GTO™ IntelliMAX™ ISOPLANAR™ Making Small Speakers Sound Louder and Better™ MegaBuck™ MICROCOUPLER™ MicroFET™ MicroPak™ MicroPak2™ MillerDrive™ MotionMax™ mWSaver OptoHiT™ **OPTOLOGIC[®] OPTOPLANAR[®]**

()_® PowerTrench[®] PowerXS^{TI} Programmable Active Droop™ QFET QS™ Quiet Series™ RapidConfigure™ \bigcirc TM Saving our world, 1mW/W/kW at a time™ SignalWise™ SmartMax™ SMART START™ Solutions for Your Success™ SPM[®] **STEALTH™** SuperFET[®] SuperSOT™-3 SuperSOT™-6 SuperSOT™-8 SupreMOS[®] SyncFET™

TinyBoost[®] TinyBuck[®]

Sync-Lock™

 TinyBuck[™]

 TinyCalc[™]

 TinyLogic[®]

 TINYOPTO[™]

 TinyPower[™]

 TinyPWM[™]

 TinyWire[™]

 Transic[™]

 TriFault Detect[™]

 TRUECURRENT[®]*

 µSerDes[™]

UHC[®] Ultra FRFET™ UniFET™ VCX™ VisualMax™ VoltagePlus™ XS™

* Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN, FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS ON NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

efinition of Terms						
Datasheet Identification	Product Status	Definition				
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.				
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.				
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.				
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.				

Rev. 166

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor haves against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly ori indirectly, any claim of personal injury or death

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

onsemi:

ISL9V5045S3ST ISL9V5045S3ST-F085C